

**April 2015** 

### FDD8445

# N-Channel PowerTrench® MOSFET 40V, 50A, 8.7m $\Omega$

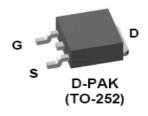
#### **Features**

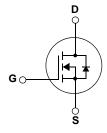
- $R_{DS(ON)} = 6.7 \text{ m}\Omega$  (Typ),  $V_{GS} = 10V$ ,  $I_D=50A$
- $Q_{g(10)} = 45nC \text{ (Typ)}, V_{GS}=10V$
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- RoHS Compliant



### **Applications**

- Powertrain Management
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems





### **Absolute Maximum Ratings** T<sub>c</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DSS}$	Drain to Source Voltage	40	V
$V_{GS}$	Gate to Source Voltage	±20	V
	Drain Current Continuous (V <sub>GS</sub> =10v) (Note 1)	70	Α
I <sub>D</sub>	Continuous ( $V_{GS}=10v$ , with $R_{\theta JA}=52^{\circ}C/W$ )	15.2	Α
	Pulsed	Figure 4	
E <sub>AS</sub>	SinglePulseAvalancheEnergy (Note2)	144	mJ
В	Power Dissipation	79	W
$P_{D}$	Derate above 25°C	0.53	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to +175	°C

#### **Thermal Characteristics**

F	$R_{ heta JC}$	Thermal Resistance, Junction to Case	1.9	°C/W
F	$R_{ heta JA}$	Thermal Resistance, Junction to Ambient TO-252, lin <sup>2</sup> copper pad area	52	°C/W

## **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8445	FDD8445	TO-252AA	13"	16mm	2500 units

### **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Chara	acteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$		40	-	-	V
	Zara Cata Valtaga Drain Current	V <sub>DS</sub> = 32V		-	-	1	μΑ
IDSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T <sub>J</sub> =150°C	-	-	250	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

#### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2	2.8	4	V
		$I_D = 50A, V_{GS} = 10V$	-	6.7	8.7	
R <sub>DS(ON)</sub>	Drain to Source On Resistance	$I_D = 50A$ , $V_{GS} = 10V$ , $T_J = 175$ °C	-	12.5	16.3	mΩ

#### **Dynamic Characteristics**

-							
C <sub>ISS</sub>	Input Capacitance	\/ OF\/ \/	0)/	-	3040	4050	pF
Coss	Output Capacitance	$V_{DS} = 25V, V_{GS}$ = 1MHz	= 00,	-	295	390	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance	1 - 1101112		-	178	270	pF
$R_G$	Gate Resistance	f = 1MHz		-	1.7	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	45	59	nC
Q <sub>g(5)</sub>	Total Gate Charge at 5V	$V_{GS} = 0$ to 5V		-	17	22	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0$ to $2V$	V <sub>DD</sub> =20V,	-	5.8	7.6	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		$I_D = 50A$	-	12.5	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau			-	9.5	-	nC
$Q_{qd}$	Gate to Drain "Miller" Charge			-	10.5	-	nC

<b>Electrical Characteristics</b>	$T_1 = 25$ °C unless otherwise noted
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Symbol	Parameter	Parameter Test Conditions		Тур	Max	Units
Switching	g Characteristics					
t <sub>(on)</sub>	Turn-On Time		-	-	138	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	10	-	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 20V, I_{D} = 50A$ $V_{GS} = 10V, R_{GS} = 2\Omega$	-	82	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 2\Omega$	-	26	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	9.6	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	53	ns

#### **Drain-Source Diode Characteristics**

\/	Source to Drain Diode Voltage	I <sub>SD</sub> =50A	-	-	1.25	V
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> =25A	-	•	1.0	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 50A, dI <sub>F</sub> /dt=100A/μs	-	-	39	ns
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = 50A, dI <sub>F</sub> /dt=100A/μs	-	-	38	nC

 $\begin{tabular}{ll} \textbf{Notes:} \\ \textbf{1:} & \text{Maximum package current capability is 50A.} \\ \textbf{2:} & \text{Starting T}_J = 25^{\circ}\text{C}, L=0.18\text{mH}, I_{AS}=40\text{A}. \\ \end{tabular}$ 

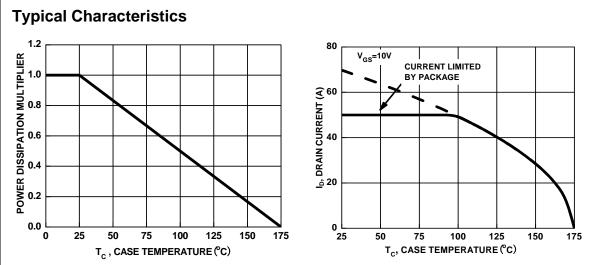


Figure 1. Normalized Power Dissipation vs Case Temperature

Figure 2. Maximum Continuous Drain Current vs Case Temperature

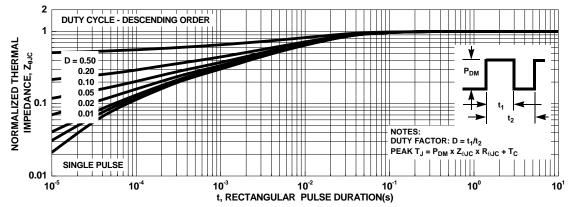


Figure 3. Normalized Maximum Transient Thermal Impedance

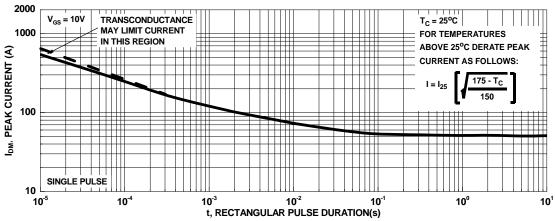
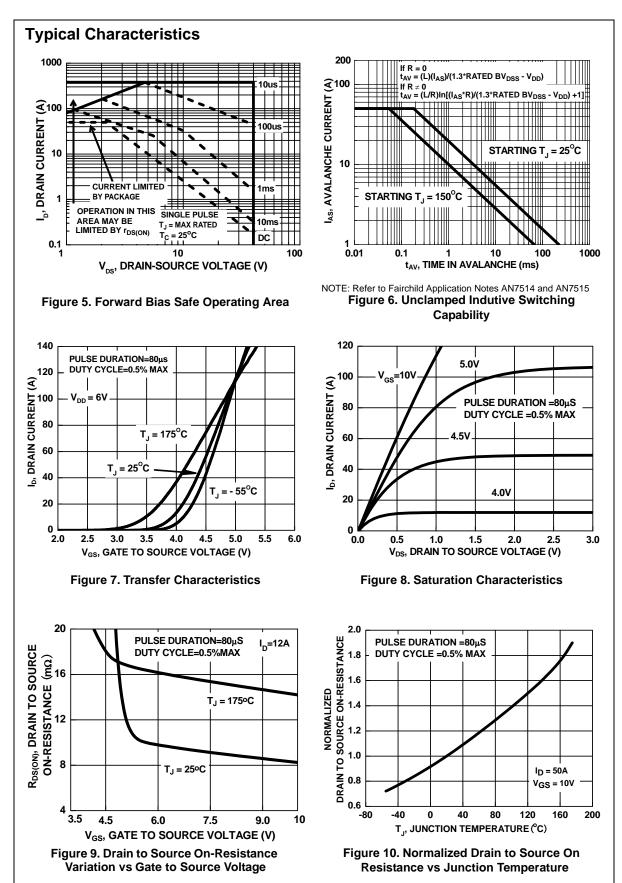


Figure 4. Peak Current Capability



## **Typical Characteristics**

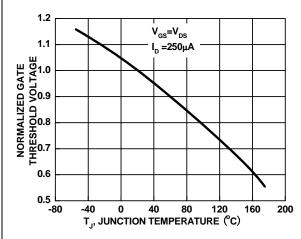


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

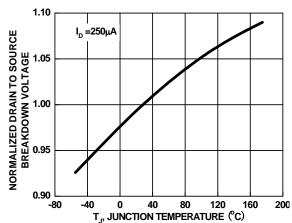


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

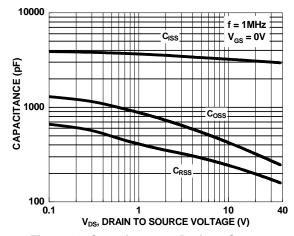


Figure 13. Capacitance vs Drain to Source Voltage

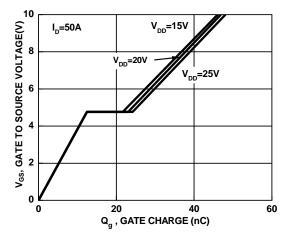


Figure 14. Gate Charge vs Gate to Source Voltage







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